

# Programmable Shunt Regulator

## LM431SA, LM431SB, LM431SC

### Description

The LM431SA / LM431SB / LM431SC are three-terminal the output adjustable regulators with thermal stability over operating temperature range. The output voltage can be set any value between  $V_{REF}$  (approximately 2.5 V) and 36 V with two external resistors. These devices have a typical dynamic output impedance of 0.2  $\Omega$ . Active output circuit provides a sharp turn-on characteristic, making these devices excellent replacement for zener diodes in many applications.

#### **Features**

- Programmable Output Voltage to 36 V
- Low Dynamic Output Impedance: 0.2 Ω (Typical)
- Sink Current Capability: 1.0 to 100 mA
- Equivalent Full-Range Temperature Coefficient of 50 ppm/°C (Typical)
- Temperature Compensated for Operation Over Full Rated Operating Temperature Range
- Low Output Noise Voltage
- Fast Turn-on Response
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

## D D

- 1. Ref
- Anode
   Cathode

SOT-89 CASE 528AH

1 2

- 1. Cathode
- 2. Ref3. Anode

2. Cathode

3. Anode

SOT-23FL CASE 318AB

1 2

M32 M3 1. Ref 1. Cathode

SOT-23 CASE 318BM 2. Ref 3. Anode

#### **ORDERING INFORMATION**

Product Number	Output Voltage Tolerance	Operating Temperature	Top Mark <sup>(1)</sup>	Package	Shipping <sup>†</sup>
LM431SACMFX	2%	–25 to +85°C	43A □	SOT-23FL 3L	Tape and Reel
LM431SACM3X			43L ⊚	SOT-23 3L	
LM431SACM32X			43G ⊚	SOT-23 3L	
LM431SBCMFX	1%		43B □	SOT-23FL 3L	
LM431SBCM3X			43M ⊚	SOT-23 3L	
LM431SBCM32X			43H ⊚	SOT-23 3L	
LM431SCCMLX	0.5%		43C	SOT-89 3L	
LM431SCCMFX			43C □	SOT-23FL 3L	
LM431SCCM3X			43N ⊚	SOT-23 3L	
LM431SCCM32X			43J ⊚	SOT-23 3L	
LM431SAIMFX	2%	−40 to +85°C	43AI	SOT-23FL 3L	
LM431SBIMFX	1%		43BI	SOT-23FL 3L	
LM431SCIMFX	0.5%		43CI	SOT-23FL 3L	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

<sup>1.</sup> SOT-23 and SOT-23FL have basically four-character marking except LM431SAIMFX. (3 letters for device code + 1 letter for date code) SOT-23FL date code is composed of 1 digit numeric or alphabetic week code adding bar-type year code.

#### **BLOCK DIAGRAM**

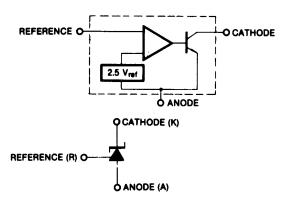


Figure 1. Block Diagram

## ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Para	Value	Unit	
V <sub>KA</sub>	Cathode Voltage	37	V	
I <sub>KA</sub>	Cathode current Range (Continuous)		-100 to +150	mA
I <sub>REF</sub>	Reference Input Current Range		-0.05 to +10.00	mA
$R_{\theta JA}$	Thermal Resistance Junction-Air (2, 3)	ML Suffix Package (SOT-89)	220	°C/W
		MF Suffix Package (SOT-23FL)	350	1
		M32, M3 Suffix Package (SOT-23)	400	
$P_{D}$	Power Dissipation (4, 5)	ML Suffix Package (SOT-89)	560	mW
		MF Suffix Package (SOT-23FL)	350	1
		M32, M3 Suffix Package (SOT-23)	310	
TJ	Junction Temperature		150	°C
т	Operating Temperature Range	All products except LM431SAIMFX	-25 to +85	°C
T <sub>OPR</sub>	Operating reinperature natige	LM431SAIMFX, SBIMFX, SCIMFX	-40 to +85	1
T <sub>STG</sub>	Storage Temperature Range	•	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 2. Thermal resistance test board
  - Size: 1.6 mm x 76.2 mm x 114.3 mm (1S0P) JEDEC Standard: JESD51-3, JESD51-7.
- 3. Assume no ambient airflow.
- 4.  $T_{JMAX} = 150$ °C; ratings apply to ambient temperature at 25°C.
- 5. Power dissipation calculation:  $P_D = (T_J T_A) / R_{\theta JA}$

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V <sub>KA</sub>	Cathode Voltage	$V_{REF}$	36	V
I <sub>KA</sub>	Cathode Current	1	100	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## **ELECTRICAL CHARACTERISTICS** (Note 6, Values are at T<sub>A</sub> = 25°C unless otherwise noted)

				LM431SA		LM431SB			LM431SC				
Symbol	Parameter	Condition	ons	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
VREF	Reference Input Voltage	$V_{KA} = V_{REF}$ , $I_{KA} = 10$	) mA	2.450	2.500	2.550	2.470	2.495	2.520	2.482	2.495	2.508	V
$\Delta V_{REF} / \Delta T$	Deviation of Reference Input Voltage	,	SOT-89 SOT-23FL		4.5	17.0		4.5	17.0		4.5	17.0	mV
	Over- Tempera- ture	IMIN ≤ IA ≤ IMAX	SOT-23		6.6	24		6.6	24		6.6	24	mV
ΔV <sub>REF</sub> / ΔV <sub>KA</sub>	Ratio of Change in Reference Input Voltage to the	I <sub>KA</sub> =10 mA	ΔV <sub>KA</sub> = 10 V-V <sub>REF</sub>		-1.0	-2.7		-1.0	-2.7		-1.0	-2.7	mV/V
	Change in Cath- ode Voltage	ΔV <sub>KA</sub> = 36 V – 10 V		-0.5	-2.0		-0.5	-2.0		-0.5	-2.0		
IREF	Reference Input Current	$I_{KA} = 10 \text{ mA}, R_1 = 1$	10 KΩ, R <sub>2</sub> = ∞		1.5	4.0		1.5	4.0		1.5	4.0	μА
$\Delta I_{REF} / \Delta T$	Deviation of Reference Input Current Over Full Temper-	$R_1 = 10 \text{ K}\Omega$	SOT-89 SOT-23FL		0.4	1.2		0.4	1.2		0.4	1.2	μА
	ature Range	$T_A = Full Range$	SOT-23		0.8	2.0		0.8	2.0		0.8	2.0	μА
IKA(MIN)	Minimum Cathode Current for Regu- lation	VKA = VREF			0.45	1.00		0.45	1.00		0.45	1.00	mA
IKA(OFF)	Off -Stage Cath- ode Current	$V_{KA} = 36 \text{ V}, V_{REF} =$	0		0.05	1.00		0.05	1.00		0.05	1.00	μА
ZKA	Dynamic Impedance	$VKA = VREF, I_{KA} = 1$ $f \ge 1.0 \text{ kHz}$	to 100 mA,		0.15	0.50		0.15	0.50		0.15	0.50	Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

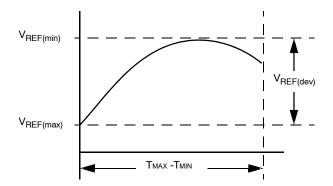
6. LM431SAI, LM431SBI, LM431SCI:  $-T_{A(min)} = -40^{\circ}C$ ,  $T_{A(max)} = +85^{\circ}C$ All other pins:  $-T_{A(min)} = -25^{\circ}C$ ,  $T_{A(max)} = +85^{\circ}C$ 

ELECTRICAL CHARACTERISTICS (Continued) (Notes 7 and 8, Values are at T<sub>A</sub> = 25°C unless otherwise noted)

				LI	LM431SAI		LM431SBI		LM431SCI				
Symbol	Parameter	Co	nditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
V <sub>REF</sub>	Reference Input Voltage	V <sub>KA</sub> = V <sub>REF</sub> , I <sub>KA</sub>	= 10 mA	2.450	2.500	2.550	2.470	2.495	2.520	2.482	2.495	2.508	V
V <sub>REF(dev)</sub>	Deviation of Reference Input Voltage Over-Temperature	V <sub>KA</sub> = V <sub>REF</sub> , I <sub>KA</sub> TMAX	= 10 mA, TMIN ≤ Ta ≤		5	20		5	20		5	20	mV
ΔV <sub>REF</sub> / ΔV <sub>KA</sub>	Ratio of Change in Reference Input Volt-	I <sub>KA</sub> = 10 mA	$\Delta V_{KA} = 10 \text{ V} - V_{REF}$		-1.0	-2.7		-1.0	-2.7		-1.0	-2.7	mV/V
	age to Change in Cathode Voltage		$\Delta V_{KA} = 36 \text{ V} - 10 \text{ V}$		-0.5	-2.0		-0.5	-2.0		-0.5	-2.0	
I <sub>REF</sub>	Reference Input Current	I <sub>KA</sub> = 10 mA, R	=10 KΩ, R <sub>2</sub> = ∞		1.5	4.0		1.5	4.0		1.5	4.0	μΑ
I <sub>REF(dev)</sub>	Deviation of Reference Input Current Over Full Temperature Range	TMIN < TA < TM	<sub>1</sub> = 10 KΩ, R <sub>2</sub> = ∞, αx		0.8	2.0		0.8	2.0		0.8	2.0	μА
I <sub>KA(MIN)</sub>	Minimum Cathode Current for Regulation	VKA = VREF			0.45	1.00		0.45	1.00		0.45	1.00	mA
I <sub>KA(OFF)</sub>	Off -Stage Cathode Current	$V_{KA} = 36 \text{ V}, V_{RE}$	<sub>EF</sub> = 0		0.05	1.00		0.05	1.00		0.05	1.00	μΑ
ZKA	Dynamic Impedance	$V_{KA} = V_{REF}, I_{KA}$ f $\geq$ 1.0 kHz	= 1 to 100 mA,		0.15	0.50		0.15	0.50		0.15	0.50	Ω

- LM431SAI, LM431SBI, LM431SCI: T<sub>A(min)</sub> = -40°C, T<sub>A(max)</sub> = +85°C
   All other pins: T<sub>A(min)</sub> = -25°C, T<sub>A(max)</sub> = +85°C
   The deviation parameters V<sub>REF(dev)</sub> and I<sub>REF(dev)</sub> are defined as the differences between the maximum and minimum values obtained over the rated temperature range. The average full-range temperature coefficient of the reference input voltage, αV<sub>REF</sub> is defined as:

$$|\alpha V_{REF}| \left(\frac{ppm}{{}^{\circ}C}\right) = \frac{\left(\frac{V_{REF(dev)}}{V_{REF}(at\ 25{}^{\circ}C)}\right) \cdot 10^{6}}{T_{MAX} - T_{MIN}}$$



where T<sub>MAX</sub>-T<sub>MIN</sub> is the rated operating free-air temperature range

 $\alpha V_{REF}$  can be positive or negative, depending on whether minimum V<sub>REF</sub> or maximum V<sub>REF</sub>, respectively, occurs at the lower temperature.

Example:

 $V_{REF(dev)}$  = 4.5 mV,  $V_{REF}$  = 2500 mV at 25°C,

 $T_{MAX} - T_{MIN} = 125^{\circ}C$  for LM431SAI.

$$|\alpha V_{REF}| = \frac{\left(\frac{4.5 \text{ mV}}{2500 \text{ mV}}\right) \cdot 10^6}{125^{\circ}C} = 14.4 \text{ ppm/}^{\circ}C$$

Because minimum V<sub>REF</sub> occurs at the lower temperature, the coefficient is positive.

## **TEST CIRCUITS**

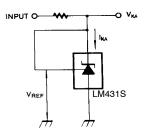


Figure 2. Test Circuit for  $V_{KA} = V_{REF}$ 

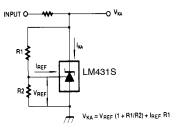


Figure 3. Test Circuit for  $V_{KA} \ge V_{REF}$ 

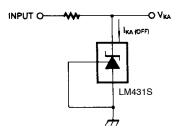


Figure 4. Test Circuit for I<sub>KA(OFF)</sub>

## **TYPICAL APPLICATIONS**

$$V_{O} = \left(1 + \frac{R_{1}}{R_{2}}\right) V_{ref}$$

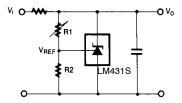


Figure 5. Shunt Regulator

$$V_{O} = \left(1 + \frac{R_{1}}{R_{2}}\right) V_{ref}$$

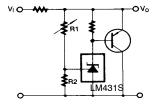


Figure 7. High Current Shunt Regulator

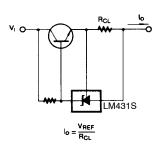
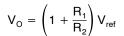


Figure 8. Current Limit or Current Source



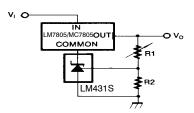


Figure 6. Output Control for Three-Terminal Fixed Regulator

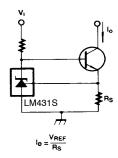


Figure 9. Constant-Current Sink

#### **TYPICAL PERFORMANCE CHARACTERISTICS**

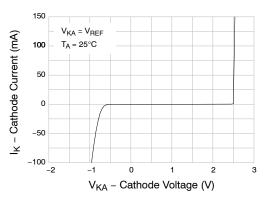


Figure 10. Cathode Current vs. Cathode Voltage

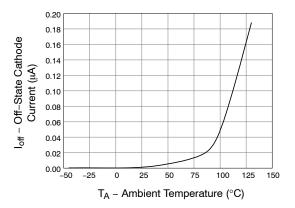


Figure 12. OFF-State Cathode Current vs. Ambient Temperature

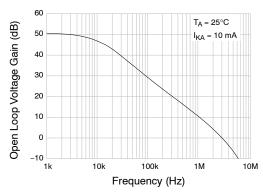


Figure 14. Frequency vs. Small Signal Voltage Amplification

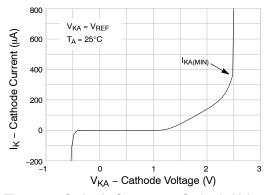


Figure 11. Cathode Current vs. Cathode Voltage

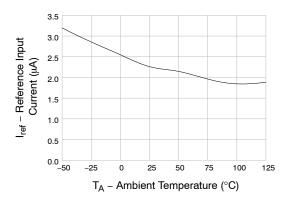


Figure 13. Reference Input Current vs. Ambient Temperature

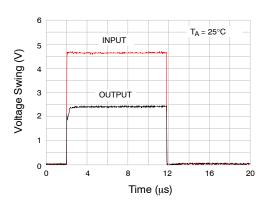


Figure 15. Pulse Response

## **TYPICAL PERFORMANCE CHARACTERISTICS**

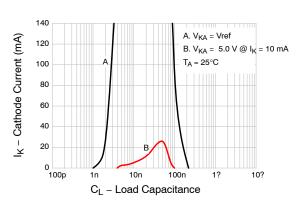


Figure 16. Stability Boundary Conditions

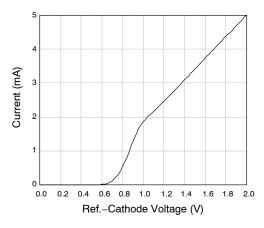


Figure 18. Reference-Cathode Diode Curve

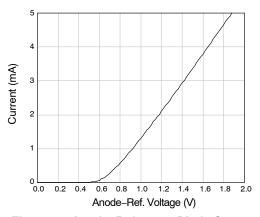


Figure 17. Anode-Reference Diode Curve

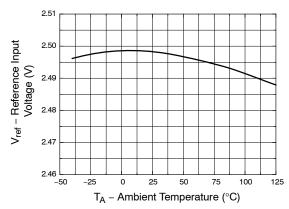


Figure 19. Reference Input Voltage vs. Ambient Temperature





SOT23-3L CASE 318AB **ISSUE A** 

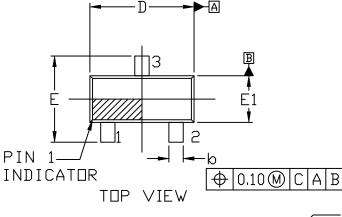
**DATE 14 DEC 2021** 

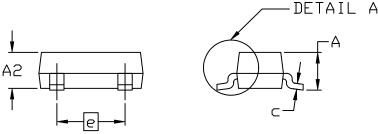


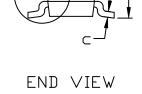
- NOTES: 1. DIM 2. CON 3. DIM
- ITES:
  DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
  CONTROLLING DIMENSION: MILLIMETERS
  DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION.
  ALLDWABLE PROTRUSION SHALL BE 0.127 mm IN EXCESS OF
  MAXIMUM MATERIAL CONDITION.
  DIMENSIONS D AND EI DO NOT INCLUDE MOLD FLASH,
  PROTRUSIONS, DR GATE BURRS. MOLD FLASH, PROTRUSIONS, DR
  GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSIONS
  D AND EI ARE DETERMINED AT DATUM F.
  ALIS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING
  PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.
  LEAD THICKNESS (c) AND LEAD WIDTH (b) INCLUDE PLATING
  THICKNESS.

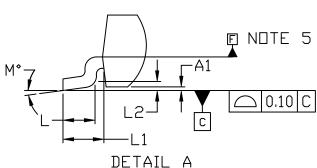
MILL INCTEDS

	MILLIMETERS						
DIM	MIN.	NDM.	MAX.				
Α			1.15				
A1	0.00		0.10				
A2	0.90	1.00	1.10				
b	0.30		0.50				
С	0.127 REF						
D	2.80	2.90	3.00				
E	2.25	2.40	2.55				
E1	1.20	1.30	1.40				
е		1.90 BSC					
L	0.30						
L1	0.55 REF						
L2	0.25 REF						
М	0*		8*				

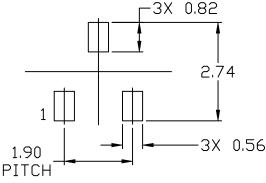








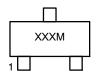
SIDE VIEW



## RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

## **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON27911H	Electronic versions are uncontrolled except when accessed directly from the Document Rep Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
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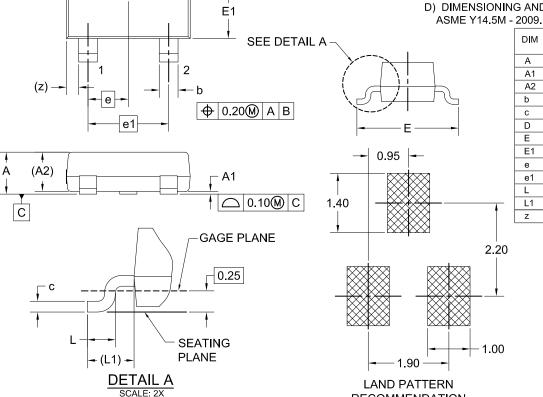


SOT-23 CASE 318BM ISSUE A

**DATE 01 SEP 2021** 



- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER

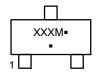


Α

В

DIM	M	IILLIMET	ERS		
D	MIN.	NOM.	MAX.		
Α			1.20		
A1	0.00	0.05	0.10		
A2	(	).93 REF			
b	0.37	0.44	0.60		
С	0.08	0.15	0.23		
D	2.72	2.92	3.12		
E	2.10	2.40	2.70		
E1	1.15	1.30	1.50		
е	(	0.95 BSC	;		
e1	,	1.90 BSC	;		
L	0.20				
L1	0.55 REF				
z	0.29 REF				

## GENERIC MARKING DIAGRAM\*



\*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

RECOMMENDATION

XXX = Specific Device Code
M = Date Code

■ = Pb–Free Package

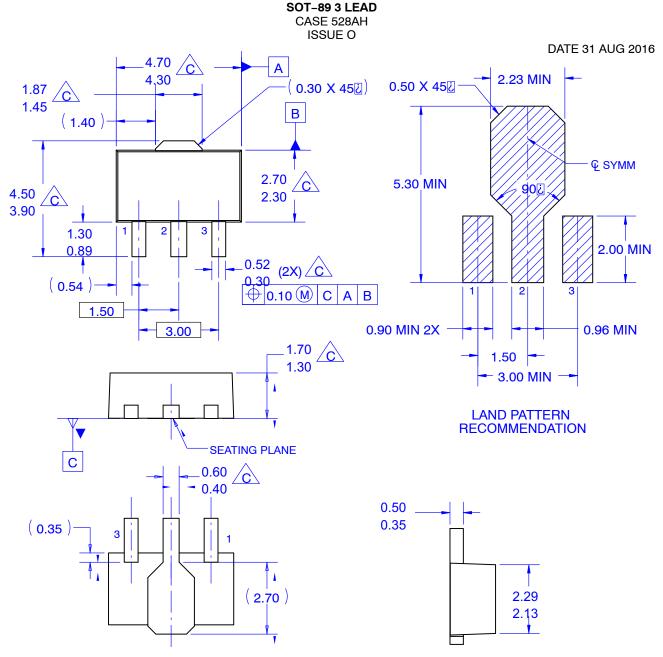
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON13784G	Electronic versions are uncontrolled except when accessed directly from the Document Reposi Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOT-23		PAGE 1 OF 1		

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NOTES: UNLESS OTHERWISE SPECIFIED.

A. REFERENCE TO JEDEC TO-243 VARIATION AA.

B. ALL DIMENSIONS ARE IN MILLIMETERS.

 $\overline{m{C}}$  DOES NOT COMPLY JEDEC STANDARD VALUE.

D. DIMENSIONS ARE EXCLUSIVE OF BURRS. MOLD FLASH AND TIE BAR PROTRUSION.

E. DIMENSION AND TOLERANCE AS PER ASME Y14.5-1994.

DOCUMENT NUMBER:	98AON13791G	Electronic versions are uncontrolled except when accessed directly from the Document Reportant Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
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